10-Bit Bus Switch with Precharged Outputs

The ON Semiconductor 74FST6800 is a 10-bit bus switch with precharged outputs. The device is CMOS TTL compatible when operating between 4.0 and 5.5 Volts. The device exhibits extremely low $R_{\rm ON}$ and adds nearly zero propagation delay. The device adds no noise or ground bounce to the system.

Features

- $R_{ON} < 4 \Omega$ Typical
- Less Than 0.25 ns-Max Delay Through Switch
- Nearly Zero Standby Current
- No Circuit Bounce
- Control Inputs are TTL/CMOS Compatible
- Pin-For-Pin Compatible With QS6800, FST6800, CBT6800
- All Popular Packages: SOIC-24, TSSOP-24, QSOP-24
- All Devices in Package TSSOP are Inherently Pb-Free*

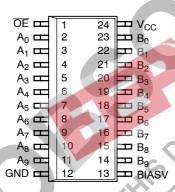


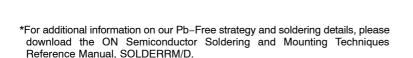
Figure 1. 24-Lead Pinout

TRUTH TABLE

ŌĒ	B ₀ -B ₉	Function
L	A ₀ -A ₉	Connect
Н	Bias V	Precharge

NOTE:

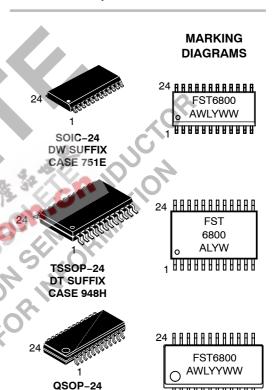
H = HIGH Voltage Level L = LOW Voltage Level





ON Semiconductor®

http://onsemi.com



A = Assembly Location
Water Let

L, WL = Wafer Lot Y, YY = Year W. WW = Work Week

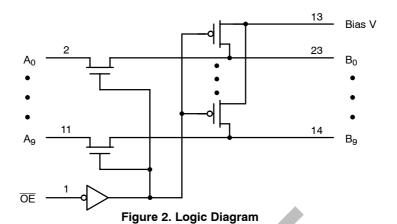
PIN NAMES

QS SUFFIX CASE 492B

	III IIANEO	
	Pin	Description
	ŌĒ	Bus Switch Enable
Γ	A	Bus A
	В	Bus B

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.



ORDERING INFORMATION

Device Order Number	Package	Shipping [†]
74FST6800DW	SOIC-24	48 Units / Rail
74FST6800DWR2	SOIC-24	2500 Units / Tape & Reel
74FST6800DT	TSSOP=24* (Pb-Free)	96 Units / Rail
74FST6800DTR2	TSSOP-24* (Pb-Free)	2500 Units / Tape & Reel
74FST6800QS	QSOP-24	96 Units / Rail
74FST6800QSR	QSOP-24	2500 Units / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. *This package is inherently Pb–Free.

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage	-0.5 to +7.0	V
VI	DC Input Voltage	-0.5 to +7.0	V
Vo	DC Output Voltage	-0.5 to +7.0	V
I _{IK}	DC Input Diode Current V _I < GND	-50	mA
I _{OK}	DC Output Diode Current V _O < GND	-50	mA
Ιο	DC Output Sink Current	128	mA
I _{CC}	DC Supply Current per Supply Pin	±100	mA
I _{GND}	DC Ground Current per Ground Pin	±100	mA
T _{STG}	Storage Temperature Range	-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
TJ	Junction Temperature Under Bias	+ 150	°C
θ_{JA}	Thermal Resistance SOIC TSSOP QSOP	125 170 200	°C/W
MSL	Moisture Sensitivity	Level 1	
F _R	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage Human Body Model (Note 1) Machine Model (Note 2) Charged Device Model (Note 3)	> 2000 > 200 N/A	V
I _{Latchup}	Latchup Performance Above V _{CC} and Below GND at 85°C (Note 4)	±500	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. Tested to EIA/JESD22-A114-A.
- Tested to EIA/JESD22-A115-A.
 Tested to JESD22-C101-A.
- 4. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	ı	Parameter			Unit
V _{CC}	Supply Voltage	Operating, Data Retention Only	4.0	5.5	V
VI	Input Voltage	(Note 5)	0	5.5	٧
Vo	Output Voltage	(HIGH or LOW State)	0	5.5	V
T _A	Operating Free-Air Temperature		-40	+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate Switch I/O	Switch Control Input $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0	DC 5	ns/V

^{5.} Unused control inputs may not be left open. All control inputs must be tied to a high or low logic input voltage level.

DC ELECTRICAL CHARACTERISTICS

			v _{cc}	T _A = -	40°C to	+85°C	
Symbol	Parameter	Conditions	(V)	Min	Тур*	Max	Unit
V _{IK}	Clamp Diode Resistance	I _{IN} = -18mA	4.5			-1.2	V
V _{IH}	High-Level Input Voltage		4.0 to 5.5	2.0	.0		V
V _{IL}	Low-Level Input Voltage		4.0 to 5.5			0.8	V
l _l	Input Leakage Current	$0 \le V_{IN} \le 5.5 V$	5.5)	±1.0	μΑ
l _{OZ}	OFF-STATE Leakage Current	$0 \le A, B \le V_{CC}$	5.5		17	±1.0	μΑ
R _{ON}	Switch On Resistance (Note 6)	V _{IN} = 0 V, I _{IN} = 64 mA	4.5		4	7	Ω
		V _{IN} = 0 V, I _{IN} = 30 mA	4.5	,0,	4	7	
		V _{IN} = 2.4 V, I _{IN} = 15 mA	4.5		8	15	
		V _{IN} = 2.4 V, I _{IN} = 15 mA	4.0		11	20	
Icc	Quiescent Supply Current	V _{IN} = V _{CC} or GND, I _{OUT} = 0	5.5			3	μΑ
ΔI_{CC}	Increase In I _{CC} per Input	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5			2.5	mA

AC ELECTRICAL CHARACTERISTICS

	THI TP	"TR"		• •	C to +85°0 I = RD = 5		
	OR		V _{CC} = 4	.5–5.5 V	V _{CC} =	4.0 V	
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t _{PHL} , t _{PLH}	Prop Delay Bus to Bus (Note 7)	V _I = OPEN		0.25		0.25	ns
t _{PZH} , t _{PZL}	Output Enable Time, I _{OE} to Bus A, B	Bias V = GND V_I = OPEN for t_{PZH}	1.0	5.1		5.6	ns
t _{PHZ} , t _{PLZ}	Output Disable Time, I _{OE} to Bus A, B	Bias V = GND V _I = OPEN for t _{PHZ}	1.0	5.5		5.5	ns

^{7.} This parameter is guaranteed by design but is not tested. The bus switch contributes no propagation delay other than the RC delay of the typical On resistance of the switch and the 50 pF load capacitance, when driven by an ideal voltage source (zero output impedance).

CAPACITANCE (Note 8)

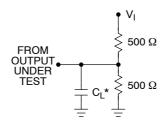
Symbol	Parameter	Conditions	Тур	Max	Unit
C _{IN}	Control Pin Input Capacitance	V _{CC} = 5.0 V	3		pF
C _{I/O}	A/B Port Input/Output Capacitance	V _{CC} , OE = 5.0 V	5		pF

^{8.} $T_A = +25$ °C, f = 1 MHz, Capacitance is characterized but not tested.

^{*}Typical values are at V_{CC} = 5.0 V and T_A = 25°C.

6. Measured by the voltage drop between A and B pins at the indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins.

AC Loading and Waveforms



NOTES:

- 1. Input driven by 50 Ω source terminated in 50 $\Omega.$
- 2. CL includes load and stray capacitance.

Figure 3. AC Test Circuit

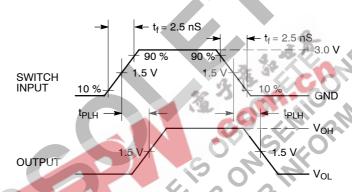


Figure 4. Propagation Delays

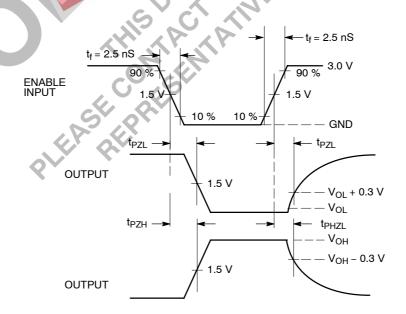
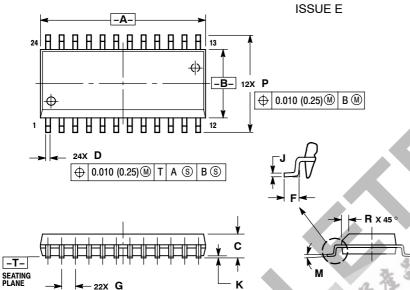


Figure 5. Enable/Disable Delays

 $[*]C_L = 50 pF$

PACKAGE DIMENSIONS

SOIC-24 **D SUFFIX** CASE 751E-04



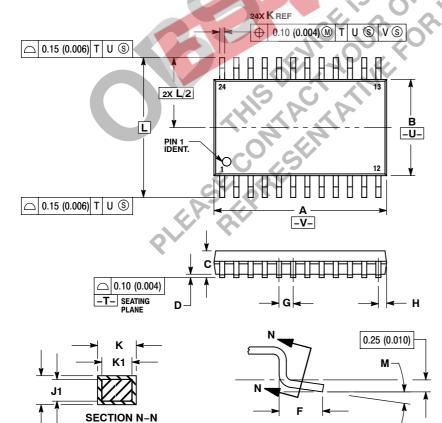
NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS A AND B DO NOT INCLUDE
 MOLD PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 (0.006)
- PER SIDE.

 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN
 EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

,					
		MILLIN	IETERS	INC	HES
	DIM	MIN	MAX	MIN	MAX
	Α	15.25	15.54	0.601	0.612
	В	7.40	7.60	0.292	0.299
	C	2.35	2.65	0.093	0.104
	D	0.35	0.49	0.014	0.019
	F	0.41	0.90	0.016	0.035
	G	1.27	BSC	0.050	BSC
	J	0.23 4	0.32	0.009	0.013
	K	0.13	0.29	0.005	0.011
-0	M	0	8°	0°	8°
- 41	Р	10.05	10 <u>.5</u> 5	0.395	0.415
B17	R	0.25	0.75	0.010	0.029
HIOP					
	IENSIC	ONING AN	D TOLER	ANCING I	PER ANSI

TSSOP-24 **DT SUFFIX** CASE 948H-01 ISSUE A

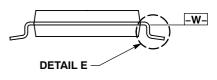


- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006)
- OH GAILE BURKS SHALL NOT EXCEED 0.15 (0.006)
 PER SIDE.
 DIMENSION B DOES NOT INCLUDE INTERLEAD
 FLASH OR PROTRUSION. INTERLEAD FLASH OR
 PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
- 0.25 (0.010) PEH SIDE.
 DIMENSION K DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN
 EXCESS OF THE K DIMENSION AT MAXIMUM
 MATERIAL CONDITION.
- MAILEMAL CUMDITION.

 6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

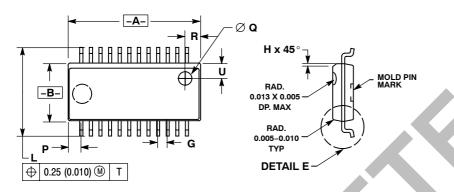
	MILLIN	MILLIMETERS INCHE		HES
DIM	MIN	MAX	MIN	MAX
Α	7.70	7.90	0.303	0.311
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65	BSC	0.026 BSC	
Н	0.27	0.37	0.011	0.015
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252	
M	0°	8°	0°	8°

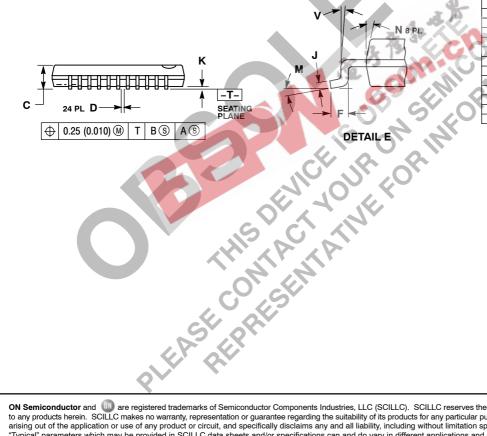


DETAIL E

PACKAGE DIMENSIONS

QSOP-24 **QS SUFFIX** CASE 492B-01 **ISSUE O**





NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH
- THE BOTTOM PACKAGE SHALL BE BIGGER THAN THE TOP PACKAGE BY 4 MILS (NOTE: LEAD SIDE ONLY). BOTTOM PACKAGE DIMENSION SHALL FOLLOW THE DIMENSION STATED IN THIS DRAWING.
- PLASTIC DIMENSIONS DOES NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 6 MILS PER
- BOTTOM EJECTOR PIN WILL INCLUDE THE COUNTRY OF ORIGIN (COO) AND MOLD CAVITY I.D.

	INCHES MILLIMETI		ETERS		
DIM	MAX	MIN	MAX	MIN	
Α	0.337	0.344	8.56	8.74	
В	0.150	0.157	3.81	3.99	
С	0.061	0.068	1.55	1.73	
D	0.008	0.012	0.20	0.31	
F	0.016	0.035	0.41	0.89	
G	0.025	BSC 🔦	0.64	BSC	
H	0.008	0.018	0.20	0.46	
J	0.0098	0.0075	0.249	0.191	
K	0.004	0.010	0.10	0.25	
L	0.230	0.244	5.84	6.20	
М	0	8°	0°	8°	
N	0°	7°	0°	7°	
P	0.027	0.037	0.69	0.94	
Q	0.035	DIA	0.89	DIA	
R	0.035	0.045	0.89	1.14	
U	0.035	0.045	0.89	1.14	
V	0°	8°	0°	8°	

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